







# TPS3762 65V ウィンドウ (OV および UV) スーパーバイザ、セルフ テストおよ びラッチ機能内蔵

### 1 特長

- SIL-3 機能安全準拠製品向け
  - IEC 61508 システムの設計に役立つ資料
  - SIL-3 までの決定論的対応能力に対応予定
  - SIL-3 までのハードウェア対応能力に対応予定
- 設計要件を満たすデバイスの柔軟性
  - 幅広い電圧スレッショルド範囲:2.7V~60V
  - 800mV オプション スレッショルドを設定するに は、外付け分割抵抗と併用
  - ヒステリシス内蔵 (2%、5%、10% のオプション)
  - 固定またはプログラム可能なリセット時間遅延
  - 固定およびプログラム可能な検出遅延
- 高電圧電源レールを監視
  - 幅広い入力電圧範囲:2.7V~65V
  - センス・ピン -65V の逆極性保護
  - 高電圧レールの電源オフに外付け部品が不要
- 12/24/48V システムでの高速 UV/OV 保護
  - 出力リセット・ラッチ機能
  - 超高速検出時間遅延オプション (5µs 未満)
  - 内蔵セルフ・テスト

# 2 アプリケーション

- 単軸と多軸のサーボ・ドライブ
- 産業用ロボット/協力ロボット
- 航空
- PLC, DCS, PAC

### 3 概要

TPS3762 は、4µA I<sub>DD</sub>、精度 0.9%、高速検出時間、内 蔵セルフテスト機能を備えた 65V 入力電圧スーパーバイ ザです。このデバイスは 12V/24V 産業用 SELV 電源レ ールに直接接続し、過電圧 (OV) および低電圧 (UV) 状 態を継続的に監視できます。また、分割抵抗を内蔵してい るため、TPS3762 はソリューション全体のサイズを最小化 できます。大きな電圧過渡の影響を受けないように、幅広 いヒステリシス電圧オプションを選択できます。 SENSE ピ ンに組み込まれたヒステリシスは、電源電圧レール監視中 のリセット信号の誤検出を防止します。

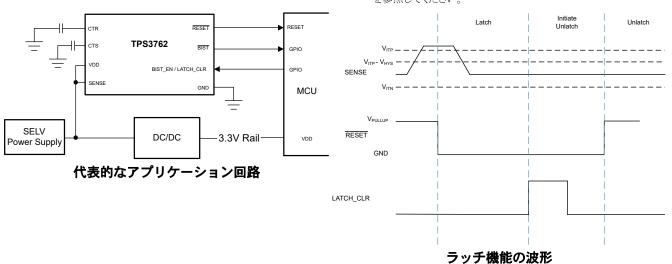
VDD ピンと SENSE ピンが独立しているため、信頼性が 高いシステムが求める冗長性を実現できます。また、 SENSE は VDD よりも高い電圧と低い電圧を監視できま す。SENSE ピンは高インピーダンス入力なので外付け抵 抗を使うこともできます。 CTS ピンおよび CTR ピンを使う ことで、RESET 信号の立ち下がり/立ち上がりエッジの遅 延を調整できます。CTS は、監視対象の電圧レールの電 圧グリッチを無視することで、デバウンシング機能として機 能します。

TPS3762 は、2.9mm × 1.6mm の SOT23 8 ピン・パッケ ージで供給されます。TPS3762 -40°C~+150°C の T<sub>4</sub> で動作します。

#### 製品情報

部品番号	パッケージ <sup>(1)</sup>	本体サイズ (公称)	
TPS3762	SOT-23 (8) (DDF)	2.9mm × 1.6mm	

パッケージの詳細については、このデータシートの末尾の外形図 を参照してください。





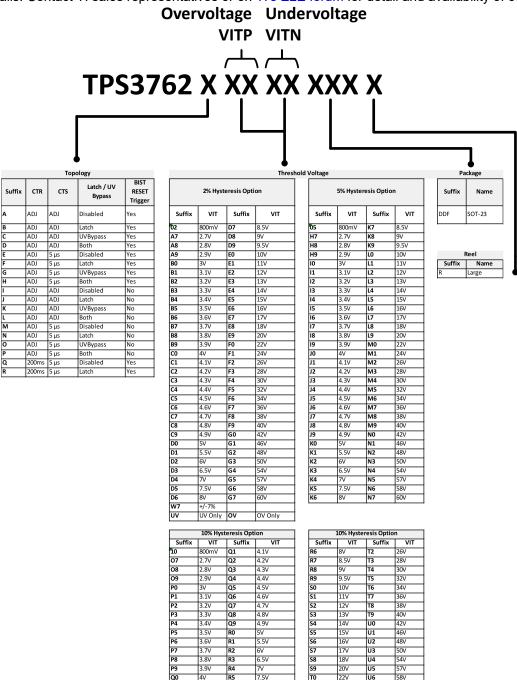
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Product Folder Links: TPS3762

### 4 Device Comparison

Device Decoder shows some of the device naming nomenclature of the TPS3762. Not all device namings will follow this nomenclature table. For a detailed breakdown of every device part number by threshold voltage options, BIST configurations, Latch configurations, CTR options, CTS options, and UVbypass, see セクション 9.1 for more details. Contact TI sales representatives or on TI's E2E forum for detail and availability of other options.



- Suffix 02, 05, and 10 with VIT of 800mV corresponds to the adjustable variant, do not have internal voltage divider
- 2. Not all TPS3762 devices can be decoded by this table. Refer to セクション 9.1 for a decoding table by part number.



# **5 Pin Configuration and Functions**

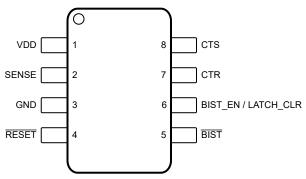


図 5-1. DDF Package, 8-Pin SOT-23, TPS3762 (Top View)

表 5-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		DESCRIPTION
VDD	1	I	<b>Input Supply Voltage:</b> Supply voltage pin. For noisy systems, bypass with a 0.1 μF capacitor to GND.
SENSE	2	ı	Sense Voltage: Connect this pin to the supply rail that must be monitored. See SENSE for more details.  Sensing Topology: Overvoltage (OV), Undervoltage (UV), or Window (OV + UV)
GND	3	-	Ground. Ground pin. All GND pins must be electrically connected to the board ground.
RESET	4	0	Output Reset Signal: RESET asserts when SENSE crosses the voltage threshold after the sense time delay, set by CTS and remains asserted for the reset time delay period after SENSE transitions out of a fault condition. For latch variants RESET remains asserted until the latch is cleared. The active low open-drain reset output requires an external pullup resistor. See セクション 7.3.3 for more details. Output topology: Open-Drain Active-Low
BIST	5	0	Built-In Self-Test: BIST asserts when a logic high input occurs on the BIST_EN / LATCH_CLR or BIST_EN pin, this initiates the internal BIST testing. BIST recovers after t <sub>BIST</sub> to signify BIST completed successfully. BIST will remain asserted for a time period longer than t <sub>BIST</sub> if there is a failure during BIST. BIST active-low open-drain output requires an external pullup resistor. See セクション 7.3.6 for more details.
BIST_EN / LATCH_CLR	6	I	Built-In Self-Test Enable and Latch Clear: A logic high input must occur on the BIST_EN / LATCH_CLR to initate BIST and clear a latched OV/UV fault. See セクション 7.3.6 and セクション 7.3.3.3 for more details.
CTR	7	0	RESET Time Delay: User-programmable reset time delay for RESET. Connect an external capacitor for adjustable time delay or leave the pin floating for the shortest delay. See セクション 7.3.4 for more details.
CTS	8	0	SENSE Time Delay: User-programmable sense time delay for SENSE. Connect an external capacitor for adjustable time delay or leave the pin floating for the shortest delay. See セクション 7.3.5 for more details.

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### **6 Specifications**

### 6.1 Specifications

### 6.2 Absolute Maximum Ratings

over operating free-air temperature range, unless otherwise noted (1)

		MIN	MAX	UNIT
Voltage	V <sub>DD</sub> , V <sub>SENSE(Adjustable)</sub> , V <sub>RESET</sub>	-0.3	70	V
Voltage	V <sub>SENSE</sub> (Fixed)	-65	70	V
Voltage	V <sub>CTS</sub> , V <sub>CTR</sub>	-0.3	6	V
Voltage	V <sub>BIST</sub> , V <sub>BIST_EN</sub> , V <sub>BIST_EN/LATCH_CLR</sub>	-0.3	6	V
Current	I <sub>RESET</sub> , I <sub>BIST</sub>		10	mA
Temperature (2)	Operating junction temperature, T <sub>J</sub>	-40	150	°C
Temperature (2)	Operating Ambient temperature, T <sub>A</sub>	-40	150	°C
Temperature (2)	Storage, T <sub>stg</sub>	<del>-</del> 65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
Voltage	$V_{DD}$	2.7	65	V
Voltage	V <sub>SENSE</sub> , V <sub>RESET</sub>	0	65	V
Voltage	V <sub>CTS</sub> , V <sub>CTR</sub>	0	5.5	V
Voltage	V <sub>BIST</sub> , V <sub>BIST_EN</sub> , V <sub>BIST_EN/LATCH_CLR</sub>	0	5.5	V
Current	I <sub>RESET</sub> , I <sub>BIST</sub>	0	5	mA
T <sub>J</sub> <sup>(1)</sup>	Junction temperature (free air temperature)	-40	125	°C

<sup>(1)</sup> As a result of the low dissipated power in this device, it is assumed that  $T_J = T_A$ .

#### 6.4 Thermal Information

		TPS3762	
	THERMAL METRIC (1)	DDF	UNIT
		8-PIN	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	154.6	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	77.4	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	73.2	°C/W
Ψлт	Junction-to-top characterization parameter	4.8	°C/W
ΨЈВ	Junction-to-board characterization parameter	72.9	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

<sup>(2)</sup> As a result of the low dissipated power in this device, it is assumed that  $T_J = T_A$ .



#### 6.5 Electrical Characteristics

At  $V_{DD(MIN)} \le V_{DD} \le V_{DD~(MAX)}$ , CTR = CTS = open, output  $\overline{RESET}$  pull-up resistor  $R_{PU}$  = 10 k $\Omega$ , voltage  $V_{PU}$  = 5.5 V, output  $\overline{BIST}$  pull-up resistor  $R_{PU}$  =  $\overline{BIST}$  = 10 k $\Omega$ , voltage  $V_{PU}$   $\overline{BIST}$  = 5.5 V, and load  $C_{LOAD}$  = 10 pF. The operating free-air temperature range  $T_A$  =  $-40^{\circ}C$  to  $125^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A$  =  $25^{\circ}C$  and  $V_{DD}$  = 12 V and  $V_{IT}$  = 6.5 V ( $V_{IT}$  refers to  $V_{ITN}$  or  $V_{ITP}$ ).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUP	PLY				'	
$V_{DD}$	Supply Voltage		2.7		65	V
UVLO (1)	Undervoltage Lockout	V <sub>DD</sub> rising above V <sub>DD (MIN)</sub>			2.6	V
UVLO(HYS)	Undervoltage Lockout Hysteresis	V <sub>DD</sub> falling below V <sub>DD (MIN)</sub>		500		mV
V <sub>POR(RESET)</sub>	Power on Reset Voltage (2) RESET, Active Low (Open-Drain)	V <sub>OL(MAX)</sub> = 300 mV I <sub>OUT (Sink)</sub> = 15 μA			1.4	V
V <sub>POR(BIST)</sub>	Power on Reset Voltage <sup>(2)</sup> BIST, Active Low (Open-Drain)	V <sub>OL(MAX)</sub> = 300 mV I <sub>OUT (Sink)</sub> = 15 μA			1.4	V
I <sub>DD</sub>	Supply current into V <sub>DD</sub> pin	$V_{IT} = 800 \text{ mV}$ $V_{DD \text{ (MIN)}} \le V_{DD} \le V_{DD \text{ (MAX)}}$		4	8.1	μΑ
SENSE (Inpu	t)					
I <sub>SENSE</sub>	Input current	V <sub>IT</sub> = 800 mV			200	nA
V <sub>ITN</sub>	Input Threshold Negative (Undervoltage)	V <sub>IT</sub> = 800 mV <sup>(3)</sup>	-0.9		0.9	%
V <sub>ITP</sub>	Input Threshold Positive (Overvoltage)	V <sub>IT</sub> = 800 mV <sup>(3)</sup>	-0.9		0.9	%
V <sub>HYS</sub>	Hysteresis Accuracy (4)	V <sub>IT</sub> = 0.8 V V <sub>HYS</sub> Range = 2%	1.5	2	2.5	%
RESET (Outp	out)					
I <sub>lkg(OD)</sub>	Open-Drain leakage	V <sub>RESET</sub> = 5.5 V V <sub>ITN</sub> < V <sub>SENSE</sub> < V <sub>ITP</sub>			300	nA
I <sub>lkg(OD)</sub>	Open-Drain leakage	V <sub>RESET</sub> = 65 V V <sub>ITN</sub> < V <sub>SENSE</sub> < V <sub>ITP</sub>			300	nA
V <sub>OL</sub> <sup>(5)</sup>	Low level output voltage	2.7 V ≤ VDD ≤ 65 V I <sub>RESET</sub> = 2.7 mA			350	mV

Product Folder Links: TPS3762

### 6.5 Electrical Characteristics (続き)

At  $V_{DD(MIN)} \le V_{DD} \le V_{DD \ (MAX)}$ , CTR = CTS = open, output  $\overline{RESET}$  pull-up resistor  $R_{PU}$  = 10 k $\Omega$ , voltage  $V_{PU}$  = 5.5 V, output  $\overline{BIST}$  pull-up resistor  $R_{PU}$  =  $\overline{BIST}$  = 10 k $\Omega$ , voltage  $V_{PU}$   $\overline{BIST}$  = 5.5 V, and load  $C_{LOAD}$  = 10 pF. The operating free-air temperature range  $T_A$  =  $-40^{\circ}C$  to  $125^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A$  = 25°C and  $V_{DD}$  = 12 V and  $V_{IT}$  = 6.5 V ( $V_{IT}$  refers to  $V_{ITN}$  or  $V_{ITP}$ ).

icicis to v <sub>1</sub>	eiers to v <sub>ITN</sub> or v <sub>ITP</sub> ).							
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
Capacitor T	iming (CTS, CTR)							
R <sub>CTR</sub>	Internal resistance (CTR)		3.2	4	4.8	ΜΩ		
R <sub>CTS</sub>	Internal resistance (CTS)		3.2	4	4.8	ΜΩ		
Built-in Sel	f-test							
I <sub>Ikg(BIST)</sub>	Open-Drain leakage	V <sub>BIST</sub> = 5.5 V V <sub>ITN</sub> < V <sub>SENSE</sub> < V <sub>ITP</sub>			300	nA		
I <sub>lkg(BIST)</sub>	Open-Drain leakage	$V_{\overline{\text{BIST}}} = 3.3 \text{ V}$ $V_{\overline{\text{ITN}}} < V_{\overline{\text{SENSE}}} < V_{\overline{\text{ITP}}}$			300	nA		
V <sub>BIST_OL</sub>	Low level output voltage	2.7 V ≤ VDD ≤ 65 V I <sub>BIST</sub> = 5 mA			300	mV		
V <sub>BIST_EN</sub>	BIST_EN pin logic low input				500	mV		
V <sub>BIST_EN</sub>	BIST_EN pin logic high input		1300			mV		
V <sub>BIST_EN/</sub> LATCH_CLR	LATCH_CLR pin logic low input				500	mV		
V <sub>BIST_EN/</sub>	LATCH_CLR pin logic high input		1300			mV		

- (1) When V<sub>DD</sub> voltage falls below UVLO, RESET is asserted. V<sub>DD</sub> slew rate ≤ 100 mV / μs
- (2) V<sub>POR</sub> is the minimum V<sub>DD</sub> voltage for a controlled output state. Below V<sub>POR</sub>, the output cannot be determined. V<sub>DD</sub> slew rate ≤ 100mV/µs
- (3) For adjustable voltage guidelines and resistor selection refer to **Adjustable Voltage Thresholds** in **Application and Implementation section**
- (4) Hysteresis is with respect to V<sub>ITP</sub> and V<sub>ITN</sub> voltage threshold. V<sub>ITP</sub> has negative hysteresis and V<sub>ITN</sub> has positive hysteresis.
- (5) For V<sub>OH</sub> and V<sub>OL</sub> relation to output variants refer to **Timing Figures after the Timing Requirement Table**

1

Product Folder Links: TPS3762



### 6.6 Switching Requirements

At  $V_{DD(MIN)} \le V_{DD} \le V_{DD}$  (MAX), CTR = CTS = open and enabled, output RESET pull-up resistor  $R_{PU}$  = 10 k $\Omega$ , voltage  $V_{PU}$  = 5.5 V, output BIST pull-up resistor  $R_{PU}$  BIST = 10 k $\Omega$ , voltage  $V_{PU}$  BIST = 5.5 V, and load  $C_{LOAD}$  = 10 pF. The operating free-air temperature range  $T_A$  = -40°C to 125°C, unless otherwise noted. Typical values are at  $T_A$  = 25°C and  $V_{DD}$  = 12 V and  $V_{IT}$  = 6.5 V ( $V_{IT}$  refers to  $V_{ITN}$  or  $V_{ITP}$ ).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Common Sv	vitching Requirements					
t <sub>CTR(No Cap)</sub>	RESET release time delay (CTR) <sup>(1)</sup>	VIT = 800 mV C <sub>CTR</sub> = Open 20% Overdrive from Hysteresis		350	600	μs
t <sub>CTS(No Cap)</sub>	Sense detect time delay (CTS) <sup>(2)</sup>	VIT = 800 mV C <sub>CTS</sub> = Open 20% Overdrive from V <sub>IT</sub>		85	100	μs
t <sub>SD</sub>	Startup Delay (3)	C <sub>CTR</sub> = Open		1		ms
BIST Switch	ing Requirements					
t <sub>BIST_en_pd</sub>	Rising edge of BIST_EN to BIST asserting			2.3		μs
t <sub>BIST_en_pd</sub>	Rising edge of BIST_EN to RESET asserting			2.3		μs
t <sub>BIST_recover</sub>	Rising edge of BIST to SENSE input valid	C <sub>CTR</sub> = Open, BIST = Enabled		350	600	μs
t <sub>BIST</sub>	BIST run time				3.5	ms
t <sub>SD+BIST</sub>	Startup time with BIST run time				4.5	ms
LATCH Swit	ching Requirements				1	
t <sub>BIST_EN/</sub> LATCH_CLR_R ecover	Rising edge of BIST to SENSE input valid	C <sub>CTR</sub> = Open, BIST = Disabled		10		μs

#### (1) CTR Reset detect time delay:

Overvoltage active-low output is measure from  $V_{ITP-HYS}$  to  $V_{OH}$  Undervoltage active-low output is measure from  $V_{ITN+HYS}$  to  $V_{OH}$ 

#### (2) CTS Sense detect time delay:

Overvoltage active-low output is measure from  $V_{ITP}$  to  $V_{OL}$  Undervoltage active-low output is measure from  $V_{ITN}$  to  $V_{OL}$ 

(3) During the power-on sequence, V<sub>DD</sub> must be at or above V<sub>DD (MIN)</sub> for at least t<sub>SD+BIST</sub> + t<sub>CTR</sub> before the output is in the correct state based on V<sub>SENSE</sub>.

Product Folder Links: TPS3762

 $t_{SD}$  time includes the propagation delay ( $C_{CTR}$  = Open). Capacitor on CTR will add time to  $t_{SD}$ 

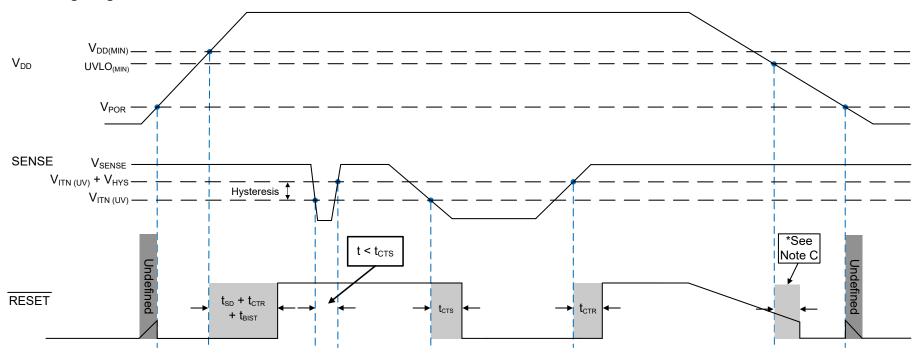
### 6.7 Timing Requirements

At  $V_{DD(MIN)} \le V_{DD} \le V_{DD (MAX)}$ , CTR = CTS = open and enabled, output  $\overline{RESET}$  pull-up resistor  $R_{PU}$  = 10 k $\Omega$ , voltage  $V_{PU}$  = 5.5 V, output  $\overline{BIST}$  pull-up resistor  $R_{PU}$   $\overline{BIST}$  = 10 k $\Omega$ , voltage  $V_{PU}$   $\overline{BIST}$  = 5.5 V, and load  $C_{LOAD}$  = 10 pF. The operating free-air temperature range  $T_A$  = -40°C to 125°C, unless otherwise noted. Typical values are at  $T_A$  = 25°C and  $V_{DD}$  = 12 V and  $V_{IT}$  = 6.5 V ( $V_{IT}$  refers to  $V_{ITN}$  or  $V_{ITP}$ ).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
Common tin	ommon timing parameters							
BIST timing	parameters							
t <sub>BIST_en Glitch</sub>	BIST_EN Glitch immunity			1.1		μs		
t <sub>BIST_en</sub>	Minimum BIST_EN input width to initate BIST			1.2	8	μs		
LATCH timir	g parameters				'			
t <sub>BIST_EN/</sub> LATCH_CLR Glitch	Latch Glitch immunity			1.5		μs		
t <sub>BIST_EN/</sub>	Latch input width to clear latch			1.6		μs		

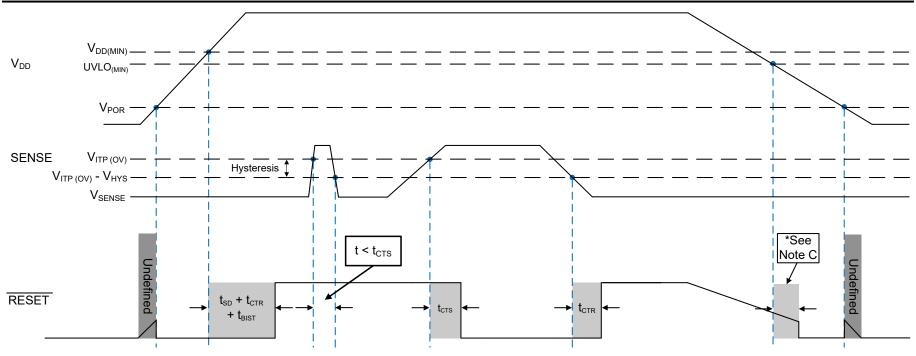


### **6.8 Timing Diagrams**



- A. The timing diagram assumes the open-drain output RESET pin is connected via an external pull-up resistor to VDD.
- B. Be advised that 🗵 6-1 shows the VDD falling slew rate is slow or the VDD decay time is much larger than the propagation detect delay (t<sub>CTR</sub>) time.
- C. RESET is asserted when VDD goes below the UVLO<sub>(MIN)</sub> threshold after the time delay, t<sub>CTR</sub>, is reached.

図 6-1. SENSE Undervoltage (UV) Timing Diagram



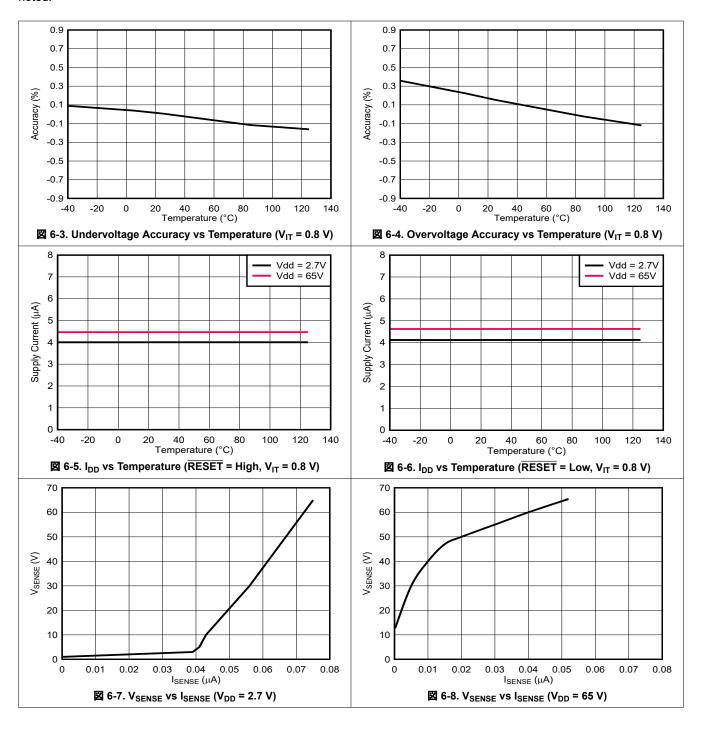
- A. The timing diagram assumes the open-drain output RESET pin is connected via an external pull-up resistor to VDD.
- B. Be advised that 🗵 6-2 shows the VDD falling slew rate is slow or the VDD decay time is much larger than the propagation detect delay (t<sub>CTR</sub>) time.
- C. RESET is asserted when VDD goes below the UVLO<sub>(MIN)</sub> threshold after the time delay, t<sub>CTR</sub>, is reached.

図 6-2. SENSE Overvoltage (OV) Timing Diagram



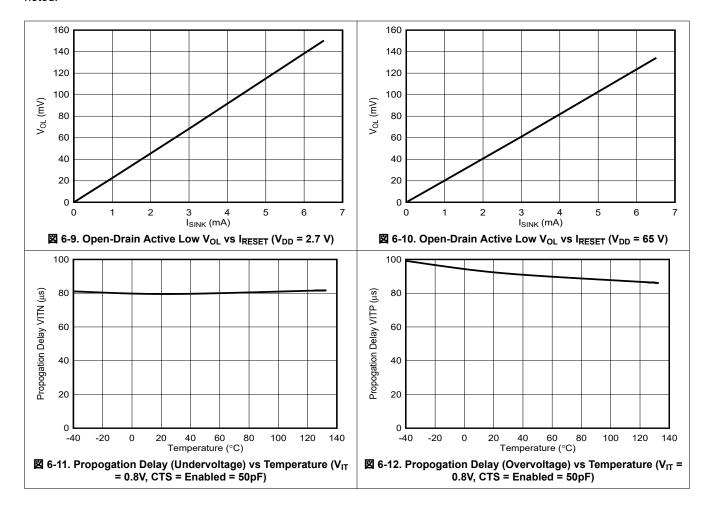
# **6.9 Typical Characteristic**

Typical characteristics show the typical performance of the TPS3762 device. Test conditions are  $T_A = 25$ °C, unless otherwise noted



# **6.9 Typical Characteristic (continued)**

Typical characteristics show the typical performance of the TPS3762 device. Test conditions are  $T_A = 25$ °C, unless otherwise noted.



### 7 Detailed Description

#### 7.1 Overview

The TPS3762 is a family of high voltage and low quiescent current voltage supervisors with overvoltage and undervoltage threshold voltage options, delay timings, Built-In Self-Test, and latch. The TPS3762 over and undervoltage thresholds are device specific and are offered in either adjustable thresholds or fixed threholds. The adjustable threshold option uses an external resistor ladder to make a voltage divider on SENSE pin which uses the internal 800 mV threshold to trigger overvoltage and undervoltage faults. The benefit of using an adjustable option with external resistors is the faster reaction speed compared to a fixed internal threshold variant. The TPS3762 fixed threshold option utilizes an integrated voltage divider to eliminate the need for external resistors and provides a lower system leakage current.

VDD, SENSE and RESET pins can support 65 V continuous operation. SENSE has -65 V reverse polarity protection. Both VDD and SENSE voltage levels can be independent of each other. TPS3762 includes a reset output latching feature that holds the output active to help system achieve safe state. Fixed and programmable sense and reset delay are available to avoid false resets and false reset releases.

### 7.2 Functional Block Diagram

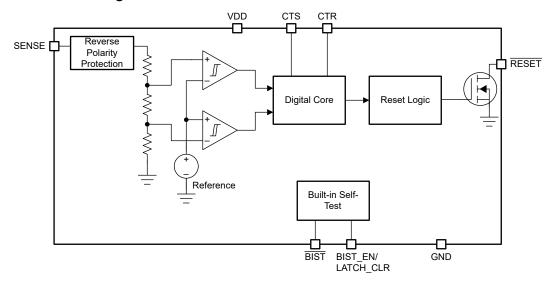


図 7-1. Fixed Threshold Functional Block Diagram

Product Folder Links: TPS3762



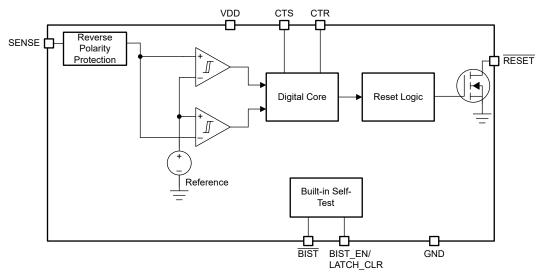


図 7-2. Adjustable Threshold Functional Block Diagram

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Product Folder Links: TPS3762

### 7.3 Feature Description

### 7.3.1 Input Voltage (VDD)

VDD operating voltage ranges from 2.7 V to 65 V. An input supply capacitor is not required for this device; however, if the input supply is noisy good analog practice is to place a 0.1  $\mu$ F capacitor between the VDD and GND.

VDD needs to be at or above V<sub>DD(MIN)</sub> for at least the start-up time delay (t<sub>SD</sub>) for the device to be fully functional.

VDD voltage is independent of  $V_{SENSE}$  and  $V_{RESET}$ , meaning that VDD can be higher or lower than the other pins.

### 7.3.1.1 Undervoltage Lockout ( $V_{POR} < V_{DD} < UVLO$ )

When the voltage on  $V_{DD}$  is less than the UVLO voltage, but greater than the power-on reset voltage ( $V_{POR}$ ), the RESET and BIST pins will be asserted, regardless of the voltage at SENSE pins.

#### 7.3.1.2 Power-On Reset ( $V_{DD} < V_{POR}$ )

When the voltage on VDD is lower than the power on reset voltage (V<sub>POR</sub>), the output signal is undefined and is not to be relied upon for proper device function.

Note: Z 7-3 and Z 7-4 assume an external pull-up resistor is connected the reset pin to VDD.

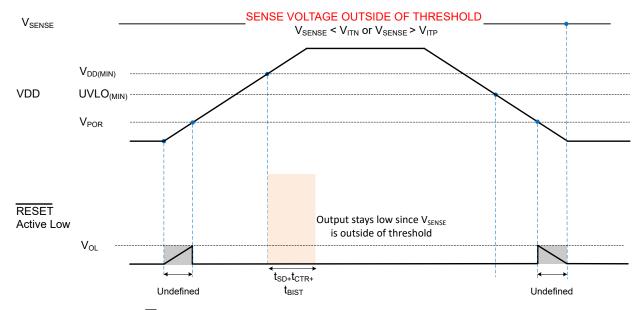


図 7-3. Power Cycle (SENSE Outside of Nominal Voltage)

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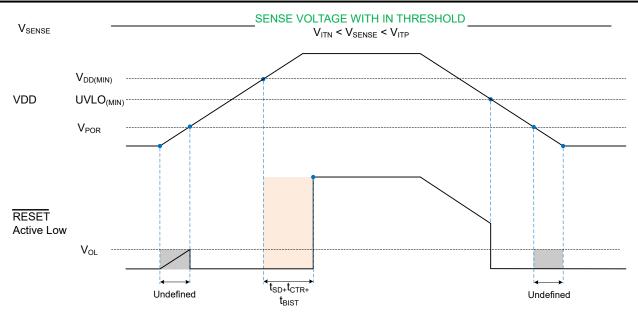


図 7-4. Power Cycle (SENSE Within Nominal Voltage)

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Product Folder Links: TPS3762

#### **7.3.2 SENSE**

The SENSE pin connects to the supply rail that is to be monitored. The sense pin on each device is configured to monitor either overvoltage (OV), undervoltage (UV), and window (OV&UV) conditions. TPS3762 device offers built-in hysteresis that provides noise immunity and maintains stable operation.

Although not required in most cases, for noisy applications good analog design practice is to place a 10 nF to 100 nF bypass capacitor at the SENSE inputs to reduce sensitivity to transient voltages on the monitored signal. SENSE can be connected directly to VDD pin.

#### 7.3.2.1 Reverse Polarity Protection

The TPS3762 has reverse polarity protection on the sense pin up to -65 V. This allows the TPS3762 to support accidental or test simulated reverse connections without damaging the device. This protection permits the TPS3762 to connect directly off of the supply prior to any reverse polarity protection diodes for accurate voltage measurement.

#### 7.3.2.2 SENSE Hysteresis

TPS3762 device offers built-in hysteresis around the UV and OV thresholds to avoid erroneous  $\overline{\text{RESET}}$  deassert. The hysteresis is opposite to the threshold voltage; for overvoltage options the hysteresis is subtracted from the positive threshold ( $V_{\text{ITP}}$ ), for undervoltage options hysteresis is added to the negative threshold ( $V_{\text{ITN}}$ ).

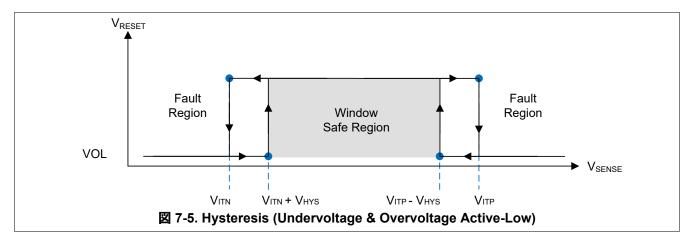


表 7-1. Common Adjustable Hysteresis Lookup Table

	TARGET		
ADJUSTABLE THRESHOLD	TOPOLOGY	RELEASE VOLTAGE (V)	DEVICE ACTUAL HYSTERESIS OPTION
800 mV	Overvoltage	784 mV	-2%
800 mV	Overvoltage	760 mV	-5%
800 mV	Overvoltage	720 mV	-10%
800 mV	Undervoltage	816 mV	2%
800 mV	Undervoltage	840 mV	5%
800 mV	Undervoltage	880 mV	10%

表 7-1 shows a sample of hysteresis for the 800 mV adjustable variant for the TPS3762.

Knowing the amount of hysteresis voltage, the release voltage for the undervoltage (UV) channel is  $(V_{ITN} + V_{HYS})$  and for the overvoltage (OV) channel is  $(V_{ITP} - V_{HYS})$ .

### Undervoltage (UV) Channel

 $V_{ITN}$  = 800 mV

Voltage Hysteresis (V<sub>HYS</sub>) = 2% = 16 mV

Hysteresis Accuracy = +1.5% to +2.5% = 16.24 mV to 16.4 mV

Release Voltage =  $V_{ITN}$  +  $V_{HYS}$  = 816.24 mV to 816.4 mV

Overvoltage (OV) Channel

 $V_{ITP} = 800 \text{ mV}$ 

Voltage Hysteresis (V<sub>HYS</sub>) = 2% = 16 mV

Hysteresis Accuracy = +1.5% to +2.5% = 16.24 mV to 16.4 mV

Release Voltage =  $V_{ITP}$  -  $V_{HYS}$  = 783.6 mV to 783.76 mV



#### 7.3.3 Output Logic Configurations

TPS3762 is a single channel device that has a single input sense pin and a single reset pin. The single reset is available with open drain topology.

#### 7.3.3.1 Open-Drain

Open-drain output requires an external pull-up resistor to hold the voltage high to the required voltage logic. Connect the pull-up resistor to the proper voltage rail to enable the output to be connected to other devices at the correct interface voltage levels.

To select the right pull-up resistor consider system  $V_{OH}$  and the Open-Drain Leakage Current ( $I_{lkg}$ ) provided in the electrical characteristics, high resistors values will have a higher voltage drop affecting the output voltage high. The open-drain output can be connected as a wired-AND logic with other open-drain signals such as another TPS3762 open-drain output pin.

#### 7.3.3.2 Active-Low (RESET)

RESET (active low) denoted with a bar above the pin label. RESET remains high voltage ( $V_{OH}$ , deasserted) (open-drain variant  $V_{OH}$  is measured against the pullup voltage) as long as sense voltage is in normal operation within the threshold boundaries and VDD voltage is above UVLO. To assert a reset sense pins needs to meet the condition below:

- For undervoltage variant the SENSE voltage need to cross the lower boundary (V<sub>ITN</sub>).
- For overvoltage variant the SENSE voltage needs to cross the upper boundary ( $V_{\text{ITP}}$ ).

### 7.3.3.3 Latching

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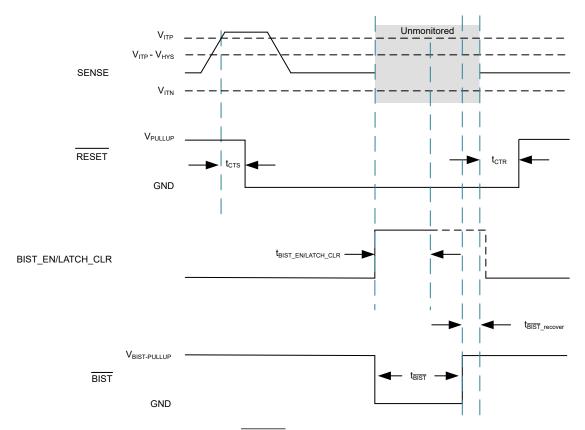


図 7-6. RESET Latch & Unlatch

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### 7.3.4 User-Programmable Reset Time Delay

TPS3762 has adjustable reset release time delay with external capacitors.

- · A capacitor on CTR programs the reset time delay of the output.
- No capacitor on this pin gives the fastest reset delay time indicated by t<sub>CTR</sub> in セクション 6.7.
- Variants such as TPS3762Q use a fixed internal time delay. check the セクション 4 to verify variant specific timing.

### 7.3.4.1 Reset Time Delay Configuration

The time delay (t<sub>CTR</sub>) can be programmed by connecting a capacitor between CTR pin and GND.

The relationship between external capacitor  $C_{CTR}$  EXT (typ) and the time delay  $t_{CTR}$  (typ) is given by  $\pm$  1.

$$t_{CTR (typ)} = R_{CTR (typ)} \times C_{CTR EXT (typ)} + t_{CTR (no cap)}$$
(1)

 $R_{CTR (typ)} = is in kilo ohms (k\Omega)$ 

 $C_{CTR\ EXT\ (typ)}$  = is given in microfarads ( $\mu F$ )

 $t_{CTR (typ)}$  = is the reset time delay (ms)

$$t_{\text{CTR (min)}} = R_{\text{CTR (min)}} \times C_{\text{CTR\_EXT (min)}} + t_{\text{CTR (no cap (min))}}$$
(2)

$$t_{CTR (max)} = R_{CTR (max)} \times C_{CTR EXT (max)} + t_{CTR (no cap (max))}$$
(3)

There is no limit to the capacitor on CTR pin. Having a too large of a capacitor value can cause very slow charge up (rise times) due to capacitor leakage and system noise can cause the internal circuit to hold RESET active.

\* Leakages on the capacitor can effect accuracy of reset time delay.

#### 7.3.5 User-Programmable Sense Delay

TPS3762 has adjustable sense release time delay with external capacitors.

- A capacitor in CTS programs the excursion detection on SENSE.
- No capacitor on this pin gives the fastest sense delay time indicated by t<sub>CTS</sub>in セクション 6.7.
- The TPS3762 comes with an optional fixed internal time delay that ignores the capacitor value at the CTS pin, check the セクション 4 to verify variant specific functionality.

#### 7.3.5.1 Sense Time Delay Configuration

The time delay (t<sub>CTS</sub>) can be programmed by connecting a capacitor between CTS pin and GND.

The relationship between external capacitor  $C_{CTS}$  EXT (typ) and the time delay  $t_{CTS}$  (typ) is given by  $\pm 3$ .

$$t_{\text{CTS (typ)}} = R_{\text{CTS (typ)}} \times C_{\text{CTS EXT (typ)}} + t_{\text{CTS (no cap)}}$$
(4)

 $R_{CTS}$  = is in kilo ohms (k $\Omega$ )

 $C_{CTS}$  EXT = is given in microfarads ( $\mu$ F)

t<sub>CTS</sub> = is the sense time delay (ms)

The sense delay varies according to three variables: the external capacitor ( $C_{CTS\_EXT}$ ), CTS pin internal resistance ( $R_{CTS}$ ) provided in Electrical Characteristics, and a constant. The minimum and maximum variance due to the constant is show in  $\pm$  5 and  $\pm$  6:

$$t_{CTS (min)} = R_{CTS (min)} \times C_{CTS EXT (min)} + t_{CTS (no cap (min))}$$
 (5)

$$t_{CTR (max)} = R_{CTS (max)} \times C_{CTS EXT (max)} + t_{CTSx (no cap (max))}$$
 (6)

The recommended maximum sense delay capacitor for the TPS3762 is limited to 10  $\mu$ F as this makes sure enough time for the capacitor to fully discharge when a voltage fault occurs. Also, having a too large of a capacitor value can cause very slow charge up (rise times) and system noise can cause the internal circuit to trip earlier or later near the threshold. This leads to variation in time delay where it can make the delay accuracy worse in the presence of system noise.

\* Leakages on the capacitor can effect accuracy of sense time delay.

#### 7.3.6 Built-In Self-Test

The TPS3762 has a Built-In Self-Test (BIST) feature that runs diagnostics internally in the device. During power-up BIST is initiated automatically after crossing  $V_{DD(min)}$ . During BIST the  $\overline{BIST}$  pin and  $\overline{RESET}$  output asserts low and deasserts if the  $\overline{BIST}$  test completes successfully indicating no internal faults in the device. The length of the BIST and  $\overline{BIST}$  assertion is specified by  $t_{\overline{BIST}}$ . If BIST is not successful, the  $\overline{BIST}$  pin will say asserted low signifying an internal fault. The  $\overline{RESET}$  output will stay assert on  $\overline{BIST}$  failure. During BIST, the device is not monitoring the SENSE pin for faults and the  $\overline{RESET}$  is not dependent on the SENSE pin voltage. The  $\overline{BIST}$  sequence of internal tests verifies the internal signal chain of the device by checking for faults on the internal comparators on the SENSE pin, bandgap voltage, and the  $\overline{RESET}$  output. See  $\boxtimes$  7-7 for more details.



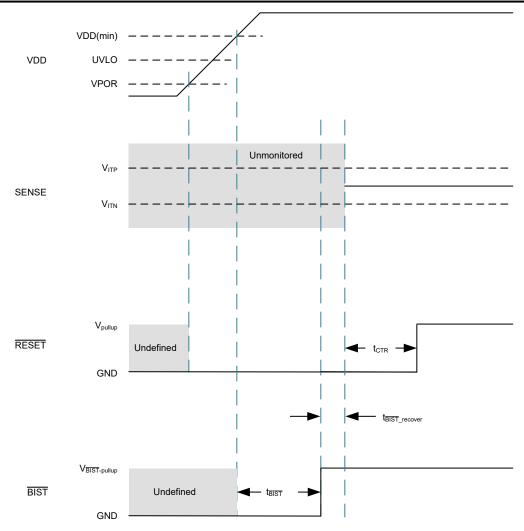


図 7-7. TPS3762 Start-Up Sequence

After a successful power-up sequence, BIST can be initiated any time with a logic high input ( $V_{BIST\_EN}$  or  $V_{BIST\_EN/LATCH\_CLR} > 1.3$  V) on the BIST\_EN / LATCH\_CLR pin. BIST initiates and the  $\overline{BIST}$  pin asserts only if the SENSE pin is not in a overvoltage or undervoltage fault mode. During this BIST test time period,  $t_{\overline{BIST}}$ ,  $\overline{BIST}$  pin asserts low to signify that  $\overline{BIST}$  has started and  $\overline{RESET}$  assertion is dependent on the device variant. Upon a successful BIST the  $\overline{BIST}$  pin and  $\overline{RESET}$  pin are deasserted. If BIST is not successful due to the internal device not working properly, the  $\overline{RESET}$  pin and  $\overline{BIST}$  pin remain asserted low signifying a fault internal to the device. See  $\boxtimes$  7-8 and for  $\boxtimes$  7-9 more details.



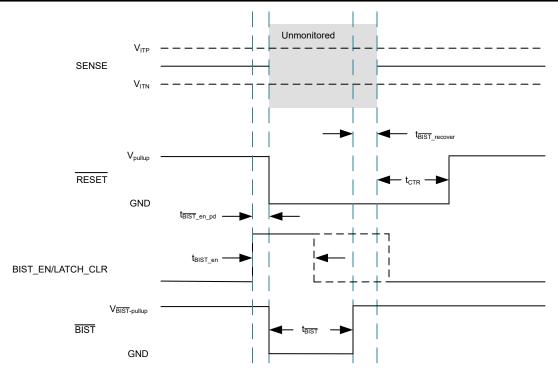


図 7-8. BIST With RESET Assertion

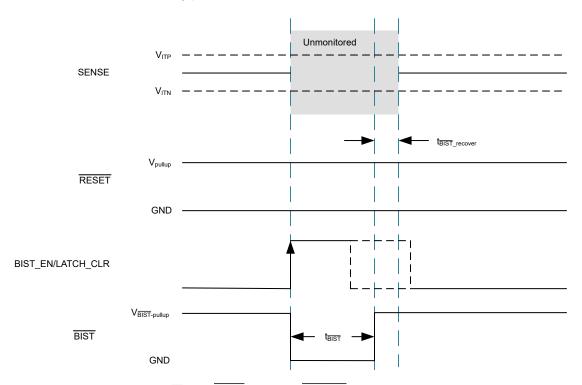


図 7-9. BIST With No RESET Assertion

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Product Folder Links: TPS3762



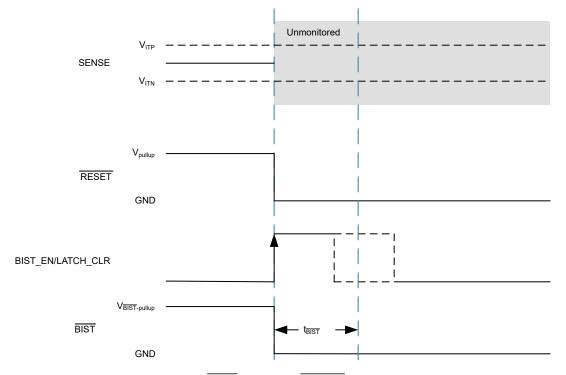


図 7-10. BIST Fail With RESET Assertion

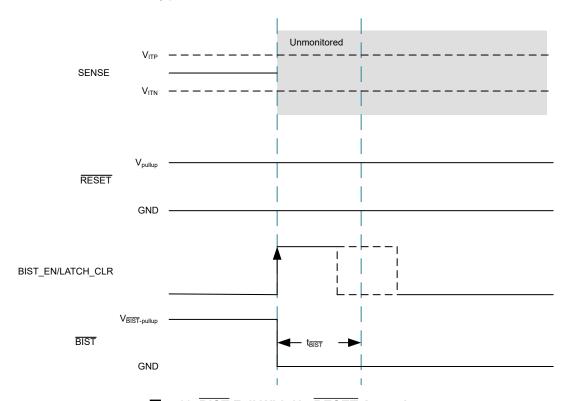


図 7-11. BIST Fail With No RESET Assertion



### 7.4 Device Functional Modes

### 表 7-2. Undervoltage Detect Functional Mode Truth Table

		iladi toltago Dotoot i						
	SENSE						OUTPUT (2)	
DESCRIPTION	PREVIOUS CONDITION	CURRENT CONDITION	CTR <sup>(1)</sup>	VDD PIN	(RESET PIN)			
Normal Operation	SENSE > V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	High			
Undervoltage Detection	SENSE > V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	Low			
Undervoltage Detection	SENSE < V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	Low			
Normal Operation	SENSE < V <sub>ITN</sub>	SENSE > V <sub>ITN</sub> + HYS	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	High			
UVLO Engaged	SENSE > V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	$V_{POR} < V_{DD} < V_{DD(MIN)}$	Low			
Below V <sub>POR</sub> , Undefined Output	SENSE > V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	V <sub>DD</sub> < V <sub>POR</sub>	Undefined			

- (1) Reset time delay is ignored in the truth table.
- (2) Open-drain active low output requires an external pull-up resistor to a pull-up voltage.

### 表 7-3. Overvoltage Detect Functional Mode Truth Table

2 7-0. Overvoitage beteet i unctional mode fruiti fubic										
	S	SENSE			OUTPUT <sup>(2)</sup> (RESET PIN)					
DESCRIPTION	PREVIOUS CONDITION	CURRENT CONDITION	CTR <sup>(1)</sup>	VDD PIN						
Normal Operation	SENSE < V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	High					
Overvoltage Detection	SENSE < V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	Low					
Overvoltage Detection	SENSE > V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	Low					
Normal Operation	SENSE > V <sub>ITN</sub>	SENSE < V <sub>ITN</sub> - HYS	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	High					
UVLO Engaged	SENSE < V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	V <sub>POR</sub> < V <sub>DD</sub> < UVLO	Low					
Below V <sub>POR</sub> , Undefined Output	SENSE < V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	V <sub>DD</sub> < V <sub>POR</sub>	Undefined					

- (1) Reset time delay is ignored in the truth table.
- (2) Open-drain active low output requires an external pull-up resistor to a pull-up voltage.

## 8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The following sections describe in detail proper device implementation, depending on the final application requirements.

### 8.2 Adjustable Voltage Thresholds

☑ 8-1 illustrates an example of how to adjust the voltage threshold with external resistor dividers. The resistors can be calculated depending on the desired voltage threshold and device part number. TI recommends using the 0.8 V voltage threshold device when using an adjustable voltage variant. This variant bypasses the internal resistor ladder.

For example, consider a 12 V rail,  $V_{MON}$ , being monitored for overvoltage (OV) using of the TPS3762D02OVDDFR variant, as shown in  $\boxtimes$  8-1. The monitored OV threshold, denoted as  $V_{MON+}$ , is the desired voltage where the device asserts the reset. For this example  $V_{MON+}=35$  V. To assert an overvoltage reset the voltage at the sense pin,  $V_{SENSE}$ , needs to be equal to the input threshold positive,  $V_{ITP}$ . For this example variant  $V_{SENSE}=V_{ITP}=0.8$  V. Using  $R_1$  and  $R_2$  the correlation between  $V_{MON+}$  and  $V_{SENSE}$  can be seen in  $\npreceq$  8. Assuming  $R_2=10$  k $\Omega$ , and  $R_1$  can be calculated as  $R_1=427.5$  k $\Omega$ .

$$V_{SENSE} = V_{MON+} \times (R_2 \div (R_1 + R_2))$$
 (7)

The TPS3762D02OVDDFR comes with variant specific 2 %, 5 %, or 10 % voltage threshold hysteresis. For the reset signal to become deasserted,  $V_{MON}$  must go below  $V_{ITP}$  -  $V_{HYS}$ . For this example variant a 2 % voltage threshold hysteresis was selected. Therefore,  $V_{MON}$  equals 34.3 V when the reset signal becomes deasserted.

There are inaccuracies that must be taken into consideration while adjusting voltage thresholds. Aside from the tolerance of the resistor divider, there is an internal resistance of the SENSE pin that can affect the accuracy of the resistor divider. Although expected to be very high impedance, users are recommended to calculate the values for the design specifications. The internal SENSE resistance ( $R_{SENSE}$ ) can be calculated by the SENSE voltage ( $R_{SENSE}$ ) divided by the SENSE current ( $R_{SENSE}$ ) as shown in  $\frac{1}{1000}$ ,  $\frac{1}{100$ 

$$I_{SENSE} = [(V_{MON} - V_{SENSE}) \div R_1] - (V_{SENSE} \div R_2)$$
(8)

$$R_{SENSE} = V_{SENSE} \div I_{SENSE}$$
 (9)

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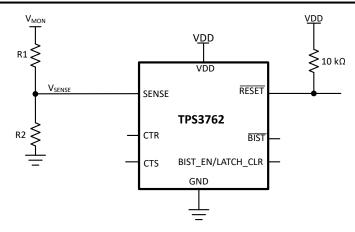


図 8-1. Adjustable Voltage Threshold with External Resistor Dividers

### 8.3 Typical Application

### 8.3.1 Design 1: SELV Power Supply Monitoring

This application is intended for the initial power stage in applications with 24 V SELV power rails. The TPS3762 utilizes high-voltage SENSE and  $V_{DD}$  inputs to monitor a 24 V SELV power rail.

⊠ 8-6 illustrates an example of how the TPS3762 is monitoring the rail voltage while being powered by it, as well.

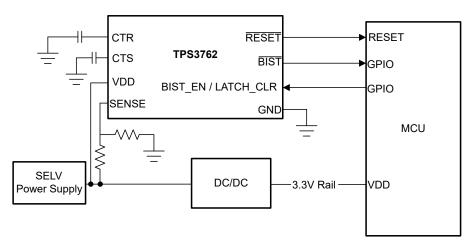


図 8-2. TPS3762 Overvoltage Supervisor with SELV Monitoring



#### 8.3.1.1 Design Requirements

#### 表 8-1. Design Parameters

PARAMETER	DESIGN REQUIREMENT
Voltage Threshold	Typical OV voltage threshold 30V.
Maximum Input Power	Operate with power supply input up to 65V
Output logic	Open-Drain
SENSE delay	>100ms
RESET delay	>300ms
Output Features	Output latching and built-in self-test

#### 8.3.1.2 Detailed Design Procedure

The TPS3762 utilizes high-voltage SENSE and V<sub>DD</sub> inputs to monitor a 24V SELV power rail.

In this design example TPS3762D02OVDDFR is used.

#### 8.3.1.2.1 Setting Voltage Threshold

The positive-going threshold voltage,  $V_{ITP}$ , is set by the device variant. In this example, the nominal supply voltage from the SELV supply is 24 V. Setting a overvoltage threshold of 30 V (~25% buffer) makes sure that the device resets before supply voltage violates the allowed boundary. The adjustable voltage variant is chosen and  $R_1$  and  $R_2$  are adusted to meet the threshold. Assuming  $R_2$  equal to 10 k $\Omega$  and  $R_1$  is calculated as 365 k $\Omega$ . For additional information on selecting resistor values see  $2000 \times 10^{-2}$  8.2. TPS3762 also supports fixed voltage threshold variants. Threshold voltage decoding can be found in Device Decoder.

#### 8.3.1.2.2 Meeting the Sense and Reset Delay

#### 8.3.1.2.3 Setting Supply Voltage

Setting the supply voltage is done by connecting the  $V_{DD}$  input directly to the 24V rail without the need for external circuitry. The device being able to handle 65 V on  $V_{DD}$  means the monitored voltage rail can handle any voltage transience up to 65 V. Good analog design practice recommends using a 0.1  $\mu$ F capacitor on the  $V_{DD}$  pin.

#### 8.3.1.2.4 Initiating Built-In Self-Test and Clearing Latch

Built-In Self-Test (BIST) is asserted on device power-up, as outlined in  $\boxtimes$  7-7. BIST can also be initiated any time by a rising edge that crosses the voltage logic high input ( $V_{BIST\_EN}$  or  $V_{BIST\_EN/LATCH\_CLR} > 1.3$  V) on the BIST\_EN / LATCH\_CLR pin, as outlined in  $\boxtimes$  7-8. Output reset latching is set by the device variant. For the device variant used in this design, TPS3762D02OVDDFR, the output has latch. Device specific output reset latching feature can be found in #none#. In order to clear the latch a logic high input on the BIST\_EN / LATCH\_CLR pin is required. When clearing latch, BIST is initiated and the RESET returns logic level high once  $t_{BIST} + t_{BIST\_recover} + t_{CTR}$  has expired, outlined in  $\boxtimes$  7-6. While  $V_{BIST\_EN/LATCH\_CLR} > 1.3$  V, the device is in latch disabled mode and the RESET will not latch for OV and UV on SENSE pin. While the device is in latch disabled mode the RESET will assert for OV and UV faults.

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### 8.3.1.3 Application Curves

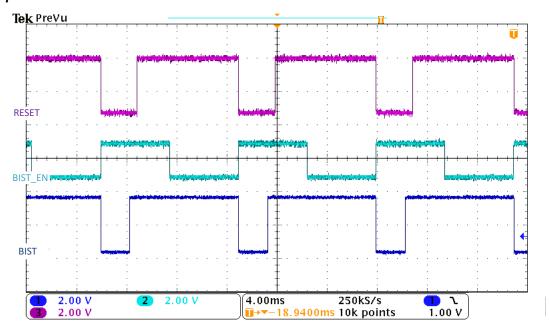


図 8-3. BIST with RESET Assertion Waveform

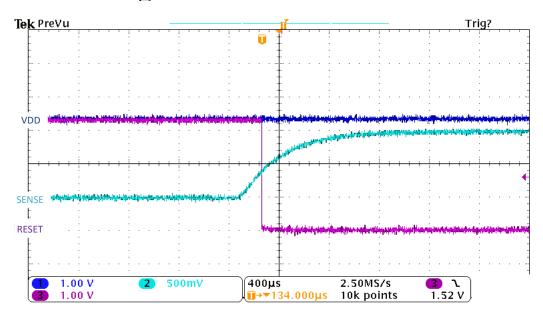


図 8-4. Overvoltage RESET Latching Waveform

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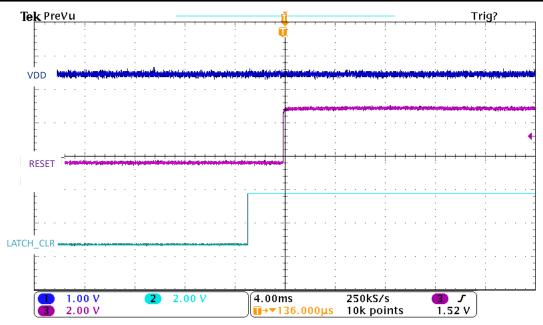


図 8-5. Overvoltage RESET Unlatching Waveform

### 8.4 Power Supply Recommendations

TPS3762 is designed to operate from an input supply with a  $V_{DD}$  voltage between 2.7 V (minimum operation) to 65 V (maximum operation). Good analog design practice recommends placing a minimum 0.1  $\mu$ F ceramic capacitor as near as possible to the  $V_{DD}$  pin.

#### 8.4.1 Power Dissipation and Device Operation

The permissible power dissipation for any package is a measure of the capability of the device to pass heat from the power source, the junctions of the IC, to the ultimate heat sink, the ambient environment. Thus, the power dissipation is dependent on the ambient temperature and the thermal resistance across the various interfaces between the die junction and ambient air.

The maximum continuous allowable power dissipation for the device in a given package can be calculated using 式 10:

$$P_{D-MAX} = ((T_{J-MAX} - T_A) / R_{\theta,JA})$$

$$(10)$$

The actual power being dissipated in the device can be represented by 式 11:

$$P_D = V_{DD} \times I_{DD} + P_{RESET} \tag{11}$$

p<sub>RESET</sub> is calculated by 式 12 or 式 13

$$p_{RESET (PUSHPULL)} = VDD - V_{RESET} \times I_{RESET}$$
 (12)

$$P_{RESET (OPEN-DRAIN)} = V_{RESET} \times I_{RESET}$$
 (13)

式 10 and 式 11 establish the relationship between the maximum power dissipation allowed due to thermal consideration, the voltage drop across the device, and the continuous current capability of the device. These two equations should be used to determine the optimum operating conditions for the device in the application.

In applications where lower power dissipation ( $P_D$ ) and/or excellent package thermal resistance ( $R_{\theta JA}$ ) is present, the maximum ambient temperature ( $T_{A-MAX}$ ) may be increased.

In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature ( $T_{A-MAX}$ ) may have to be de-rated.  $T_{A-MAX}$  is dependent on the maximum operating junction temperature ( $T_{J-MAX-OP} = 125^{\circ}C$ ), the maximum allowable power dissipation in the device package in the application ( $P_{D-MAX}$ ), and the junction-to ambient thermal resistance of the part/package in the application ( $R_{\theta JA}$ ), as given by  $\pm 14$ :

$$T_{A-MAX} = (T_{J-MAX-OP} - (R_{\theta JA} \times P_{D-MAX}))$$
(14)

#### 8.5 Layout

#### 8.5.1 Layout Guidelines

- Make sure that the connection to the VDD pin is low impedance. Good analog design practice is to place a
  greater than 0.1 μF ceramic capacitor as near as possible to the VDD pin.
- To further improve the noise immunity on the SENSE pins, placing a 10 nF to 100 nF capacitor between the SENSE pin and GND can reduce the sensitivity to transient voltages on the monitored signal.
- If a capacitor is used on CTS or CTR, place these components as close as possible to the respective pins. If the capacitor adjustable pins are left unconnected, make sure to minimize the amount of parasitic capacitance on the pins to less than 5 pF.
- Place the pull-up resistors on RESET as close to the pin as possible.
- When laying out metal traces, separate high voltage traces from low voltage traces as much as possible. If high and low voltage traces need to run close by, spacing between traces should be greater than 20 mils (0.5 mm).



 Do not have high voltage metal pads or traces closer than 20 mils (0.5 mm) to the low voltage metal pads or traces.

#### 8.5.2 Layout Example

The layout example in  $\boxtimes$  8-6 shows how the TPS3762 is laid out on a printed circuit board (PCB) with user-defined delays.

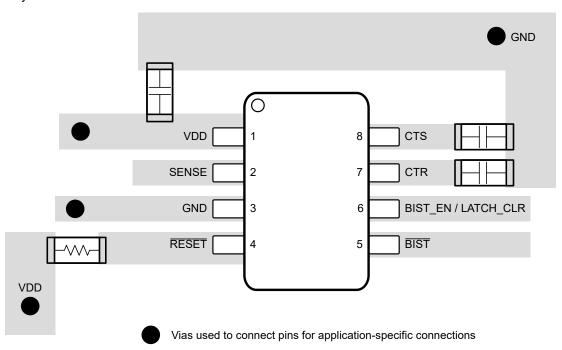


図 8-6. TPS3762 Recommended Layout

### 9 Device and Documentation Support

#### 9.1 Device Nomenclature

Device Decoder in セクション 4 describe how to decode certain device function of the device based on its part number. Not all part numbers follow this nomenclature. Use 表 9-1 as the part number decoding table for all devices.

表 9-1. Device Configuration Table

ORDERABLE PART NAME	Overvol tage (V <sub>ITP</sub> )	Overvolt age Hysteres is	Undervoltage (V <sub>ITN</sub> )	Undervoltage Hysteresis	CTR / CTS	Latch / UVbypass	BIST RESETTrigger
TPS3762D02OVDDFR	800mV	2%	N/A	N/A	ADJ / ADJ	Both Enabled	Yes

### 9.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をク リックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。 変更の詳細に ついては、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

#### 9.3 サポート・リソース

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#### 9.4 Trademarks

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#### 9.5 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うこと を推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずか に変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

#### 9.6 用語集

テキサス・インスツルメンツ用語集 この用語集には、用語や略語の一覧および定義が記載されています。

### 10 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

### Changes from Revision \* (October 2023) to Revision A (December 2023)

Page

量産データのリリース......1

#### 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: TPS3762

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資料に関するフィードバック(ご意見やお問い合わせ)を送信

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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS3762D02OVDDFR	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	62D02	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

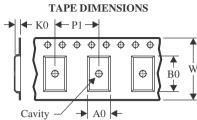
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

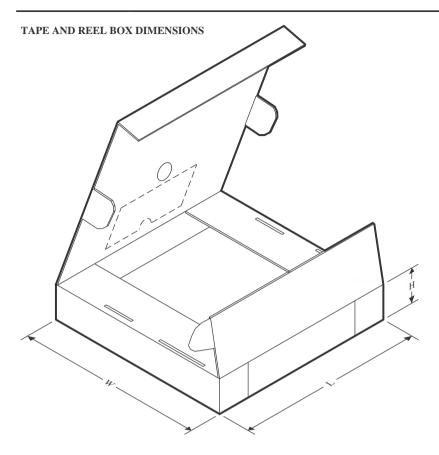


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3762D02OVDDFR	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

**PACKAGE MATERIALS INFORMATION** 

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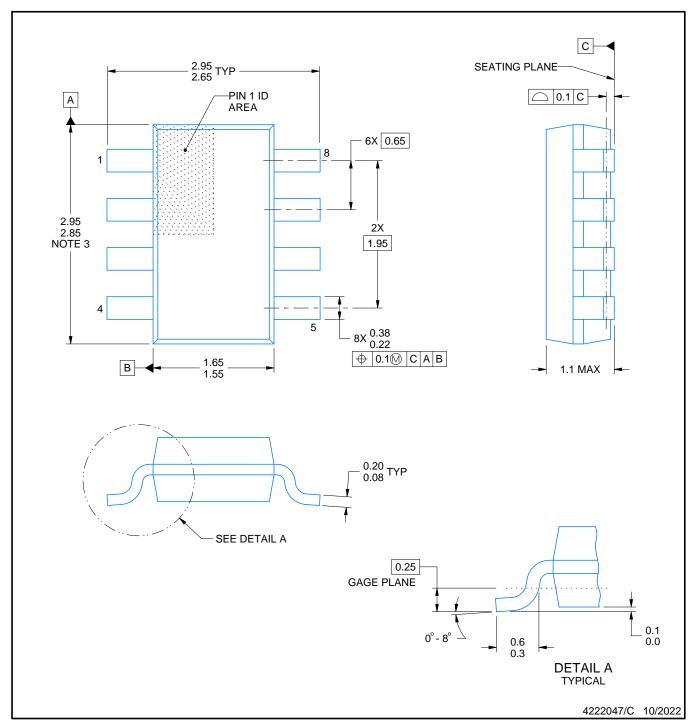


### \*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3762D02OVDDFR	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0



PLASTIC SMALL OUTLINE



### NOTES:

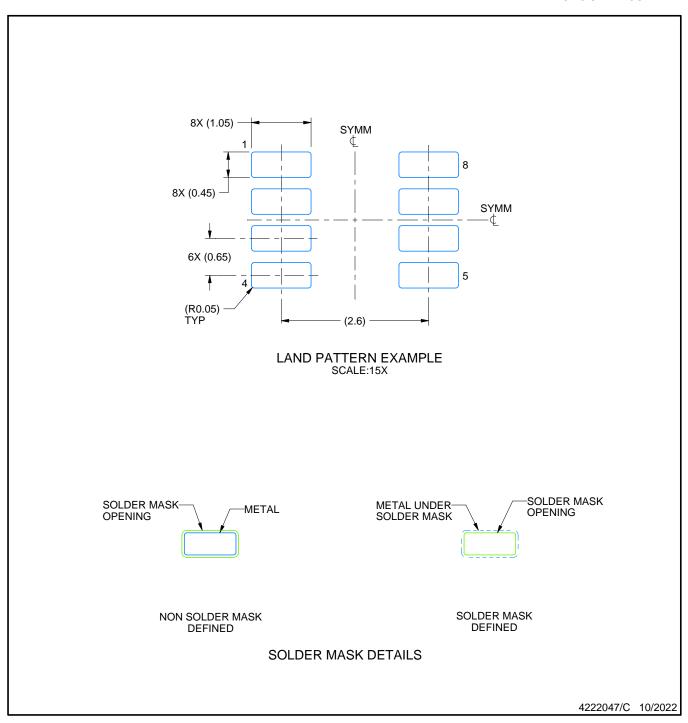
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.



PLASTIC SMALL OUTLINE

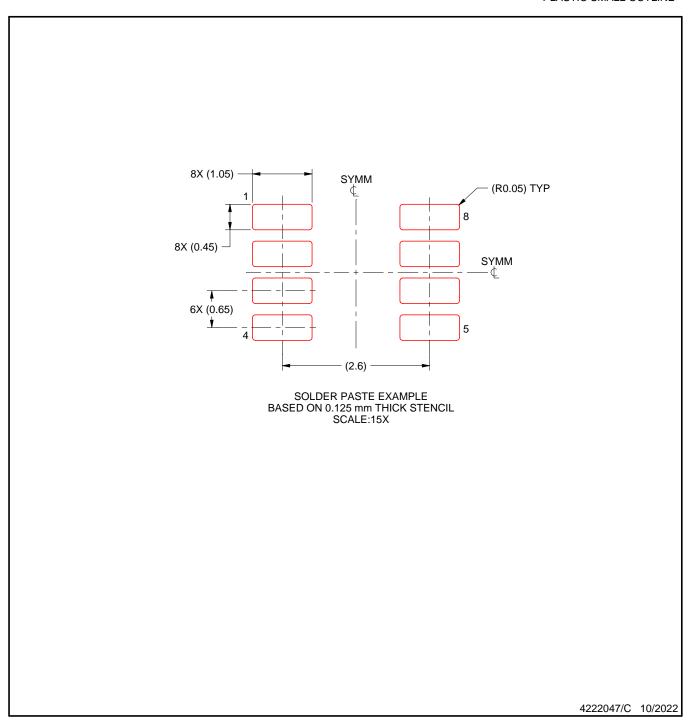


NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



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